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Features

- Max $r_{DS(on)} = 150 m\Omega$ at $V_{GS} = 4.5 V$, $I_D = -1.5 A$
- Max $r_{DS(on)}$ = 195m Ω at V_{GS} = 2.5V, I_D = -1.3A
- Max $r_{DS(on)} = 280 m\Omega$ at $V_{GS} = 1.8 V$, $I_D = -1.1 A$
- Max $r_{DS(on)}$ = 480m Ω at V_{GS} = 1.5V, I_D = -0.9A
- Control MOSFET (Q1) includes Zener protection for ESD ruggedness (>4KV Human body model)
- High performance trench technology for extremely low r_{DS(on)}
- Compact industry standard SC70-6 surface mount package
- RoHS Compliant

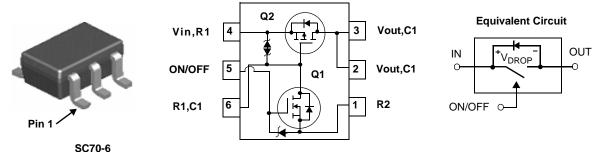


General Description

This device is particularly suited for compact power management in portable electronic equipment where 2.5V to 8V input and 1.5A output current capability are needed. This load switch integrates a small N-Channel power MOSFET (Q1) that drives a large P-Channel power MOSFET (Q2) in one tiny SC70-6 package.

Applications

- Power management
- Load switch



See Application Circuit

MOSFET Maximum Ratings T_A = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units	
V _{IN}	Gate to Source Voltage (Q2)		±8	V
V _{ON/OFF}	Gate to Source Voltage (Q1)		-0.5 to 8	V
1	Load Current -Continuous	(Note 2)	1.5	^
Load	-Pulsed	(Note 2)	6	Α
6	Power Dissipation for Single Operation	(Note 1a)	0.36	14/
P _D		(Note 1b)	0.3	W
T _J , T _{STG}	Operating and Storage Junction Temperature Range		-55 to +150	°C

Thermal Characteristics

$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient Single operation	(Note 1a)	350	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient Single operation	(Note 1b)	415	C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity 3000units	
.2L	FDG6342L	SC70-6	7"	8mm		

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	octeristics					
BVIN	V _{IN} Breakdown Voltage	$I_D = -250 \mu A, V_{ON/OFF} = 0V$	8			V
I _{Load}	Zero Gate Voltage Drain Current	$V_{IN} = -6.4V, V_{ON/OFF} = 0V$			-1	μΑ
I _{FL}	Leakage Current, Forward	$V_{IN} = 8V, V_{ON/OFF} = 0V$			10	μΑ
I _{RL}	Leakage Current, Reverse	$V_{IN} = -8V, V_{ON/OFF} = 0V$			-10	μΑ
On Chara	cteristics (note 2)					
V _{ON/OFF(th)}	Gate Threshold Voltage	$V_{IN} = V_{ON/OFF}, I_D = -250 \mu A$	0.65	0.8	1.5	V
	Statia Drain to Source On Registeres (O2)	$V_{IN} = 4.5V, I_D = -1.5A$		125	150	- - mΩ
		$V_{IN} = 2.5V, I_D = -1.3A$		150	195	
	Static Drain to Source (In Decistance (19)				000	
r _{DS(on)}	Static Drain to Source On Resistance (Q2)	V _{IN} = 1.8V, I _D = -1.1A		200	280	
r _{DS(on)}	Static Drain to Source On Resistance (Q2)	$V_{IN} = 1.8V, I_D = -1.1A$ $V_{IN} = 1.5V, I_D = -0.9A$		200 250	280 480	-
r _{DS(on)}	Static Drain to Source On Resistance (Q2) Static Drain to Source On Resistance (Q1)					Ω

Drain-Source Diode Characteristics

I _S	Maximum Continuous Drain to Source Diode Forward Current			-0.25	А
V _{SD}	Source to Drain Diode Forward Voltage $V_{ON/OFF} = 0V$, $I_S = -0.25A$ (Note 2)		-0.6	-1.2	V

NOTES:

1. R_{θJA} is determined with the device mounted on a 1in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R_{θJC} is guaranteed by design while R_{θJA} is determined by the user's board design.

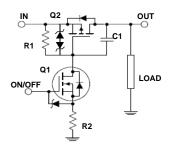
a. 350°C/W when mounted on a

1 in² pad of 2 oz copper.



2. Pulse Test: Pulse Width < 300µs, Duty cycle < 2.0%.

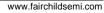
FDG6342LLoad Switch Application circuit



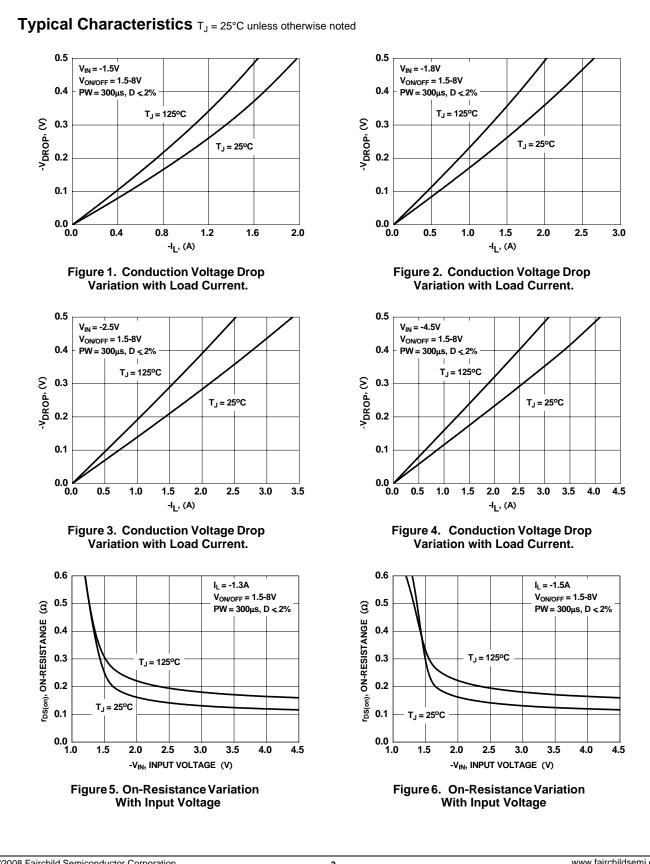
External Component Recommendation:

For additional in-rush current control, R2 and C1 can be added. For more information, see application note AN1030

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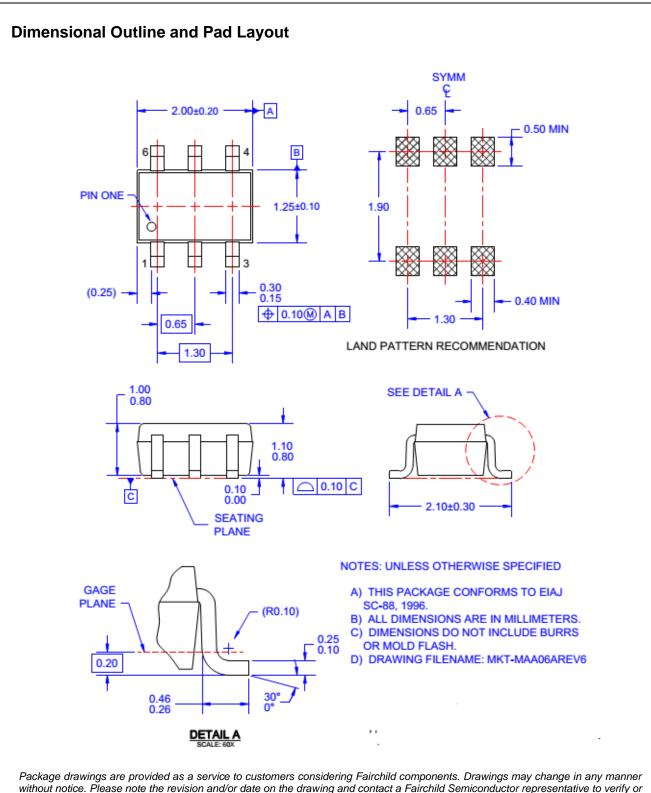


b. 415°C/W when mounted on a minimum pad of 2 oz copper.



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Rev. 172

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